

SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK3012
(F16W60VX2)**

600V 12A

FEATURES

- Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
- The static $R_{ds(on)}$ is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

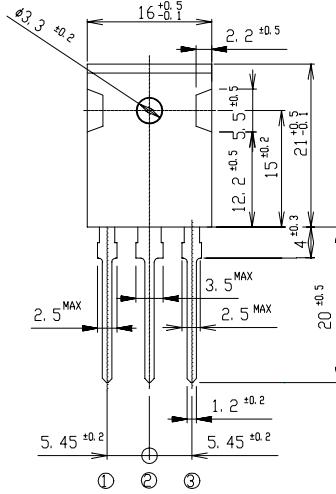
APPLICATION

- Switching power supply of AC 100-200V input
- Inverter
- Power Factor Control Circuit

OUTLINE DIMENSIONS

Case : MTO-3P

(Unit : mm)



① : G

② : D

③ : S

④ : D

RATINGS

● Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

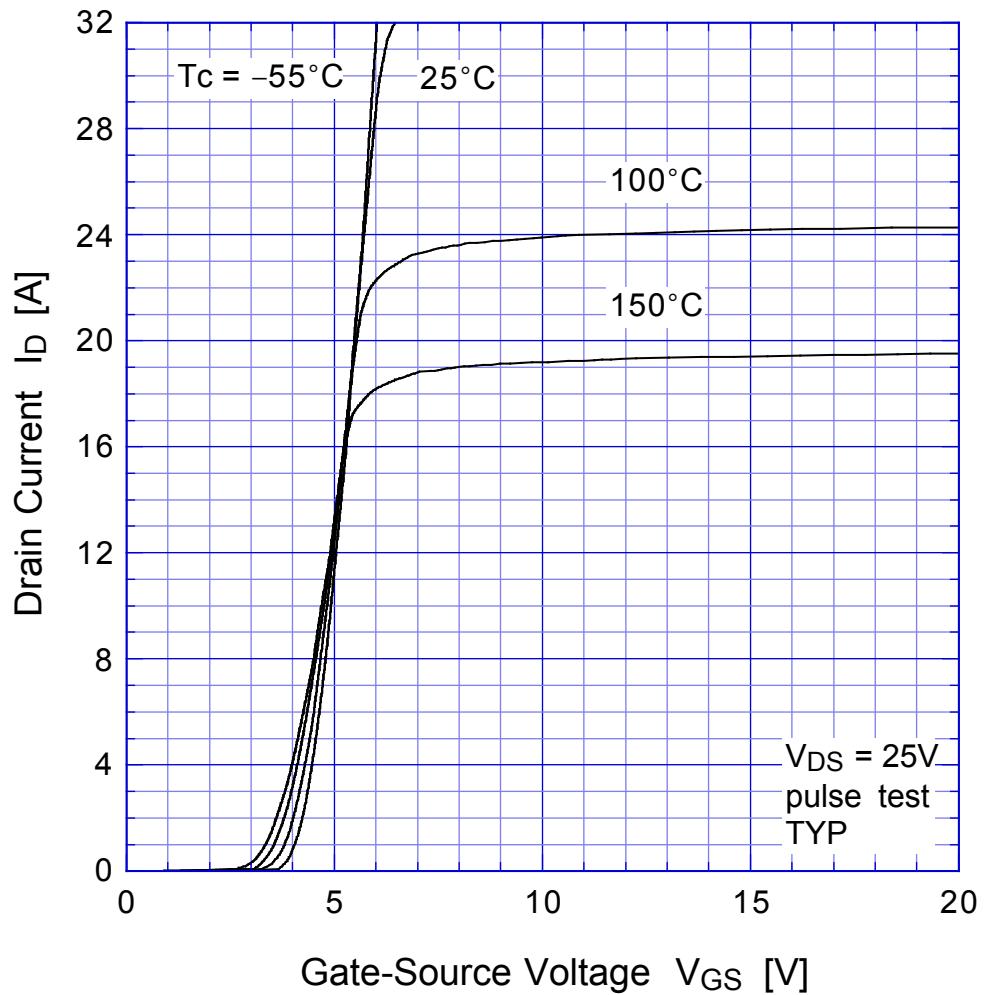
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55 ~ 150	°C
Channel Temperature	T_{ch}		150	
Drain-Source Voltage	V_{DSS}		600	V
Gate-Source Voltage	V_{GSS}		±30	
Continuous Drain Current (DC)	I_D		16	A
Continuous Drain Current (Peak)	I_{DP}		48	
Continuous Source Current (DC)	I_S		16	
Total Power Dissipation	P_T		125	W
Single Pulse Avalanche Current	I_{AS}	$T_{ch} = 25^\circ\text{C}$	16	A
Mounting Torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

●Electrical Characteristics T_c = 25°C

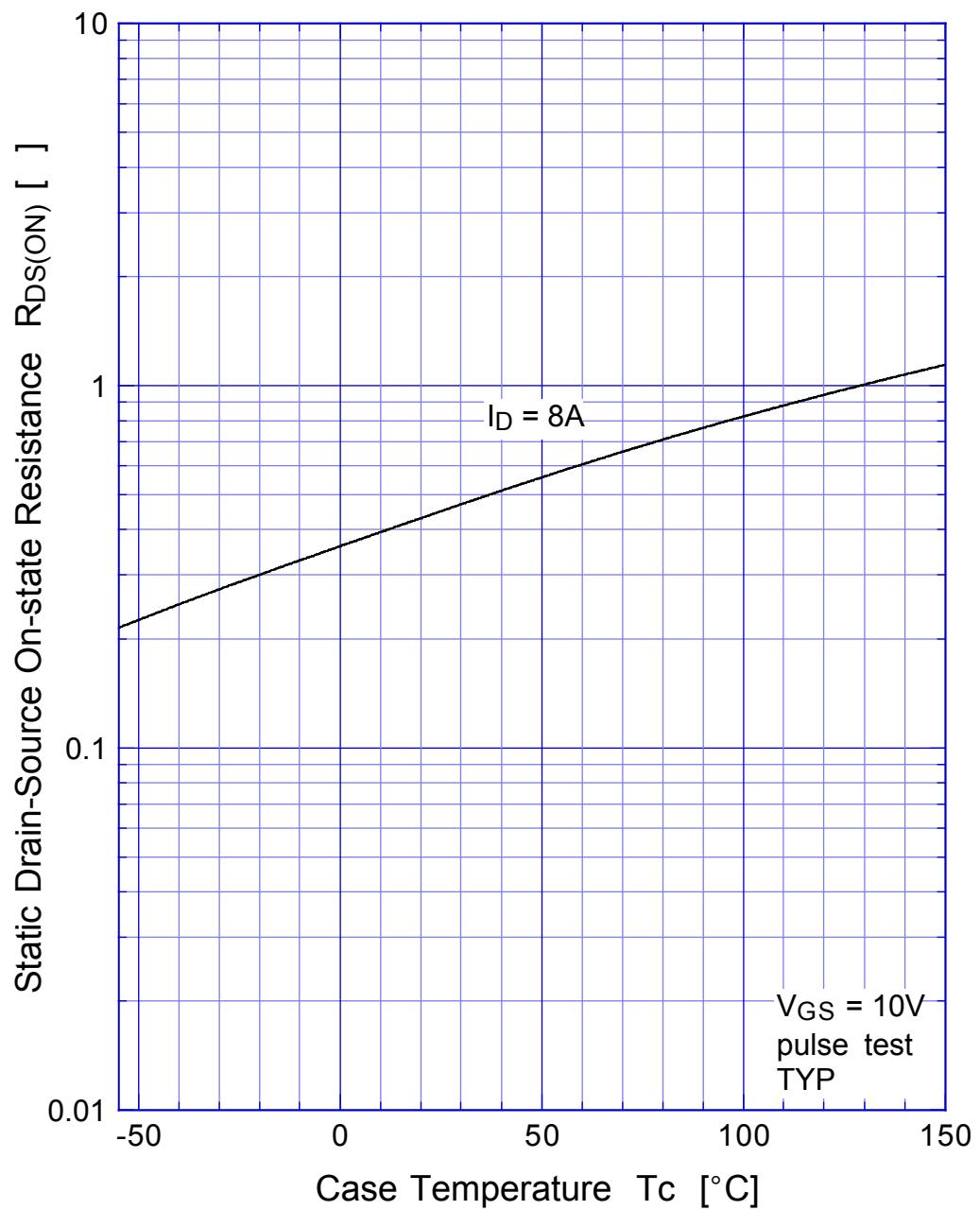
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, V _{GS} = 0V	600			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 600V, V _{GS} = 0V			250	μ A
Gate-Source Leakage Current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V			±0.1	
Forward Transconductance	g _f s	ID = 8A, V _{DS} = 10V	6.2	10.0		S
Static Drain-Source On-state Resistance	R _{D(S)ON}	ID = 8A, V _{GS} = 10V		0.45	0.6	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, V _{DS} = 10V	2.5	3	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	I _S = 8A, V _{GS} = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			1	°C/W
Total Gate Charge	Q _g	V _{GS} = 10V, ID = 16A, V _{DD} = 400V		85		nC
Input Capacitance	C _{iss}	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz		2300		pF
Reverse Transfer Capacitance	C _{rss}			180		
Output Capacitance	C _{oss}			480		
Turn-On Time	t _{on}	ID = 8A, V _{GS} = 10V, R _L = 19Ω		130	280	ns
Turn-Off Time	t _{off}			260	500	

2SK3012

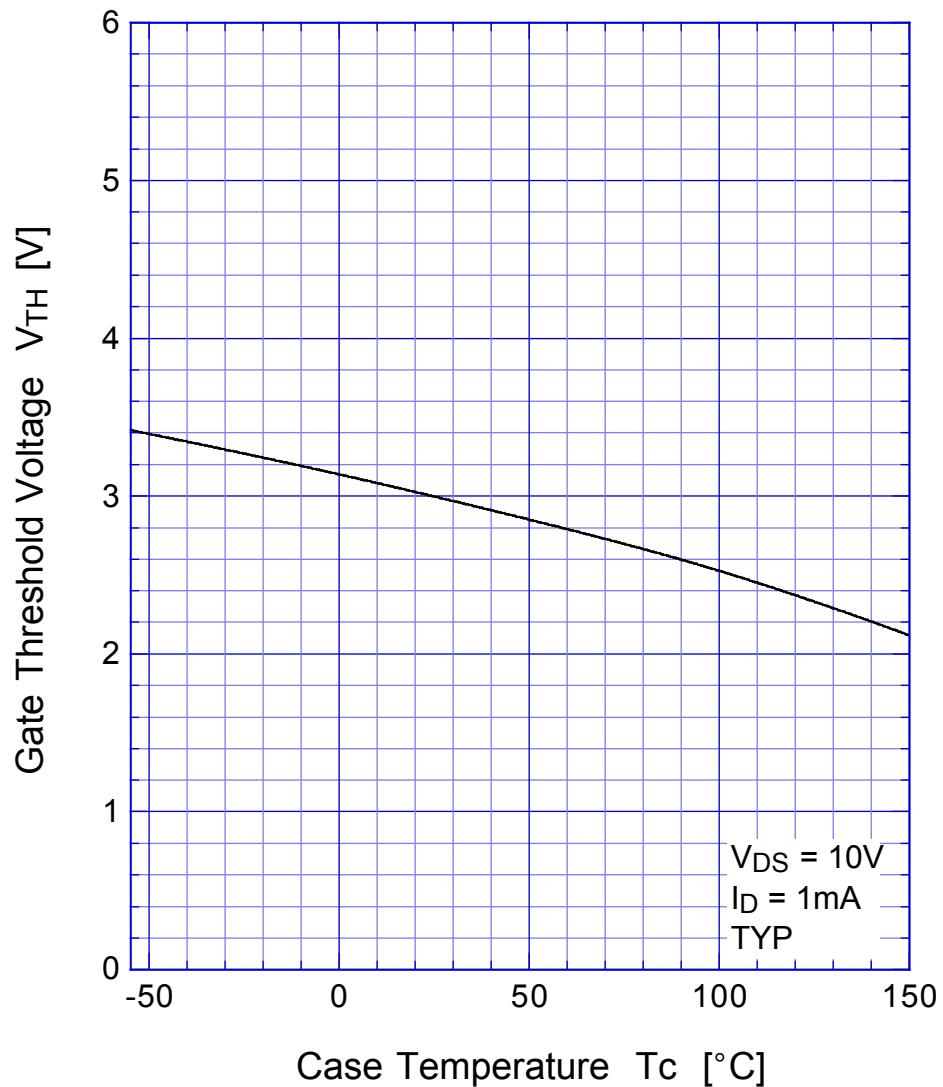
Transfer Characteristics



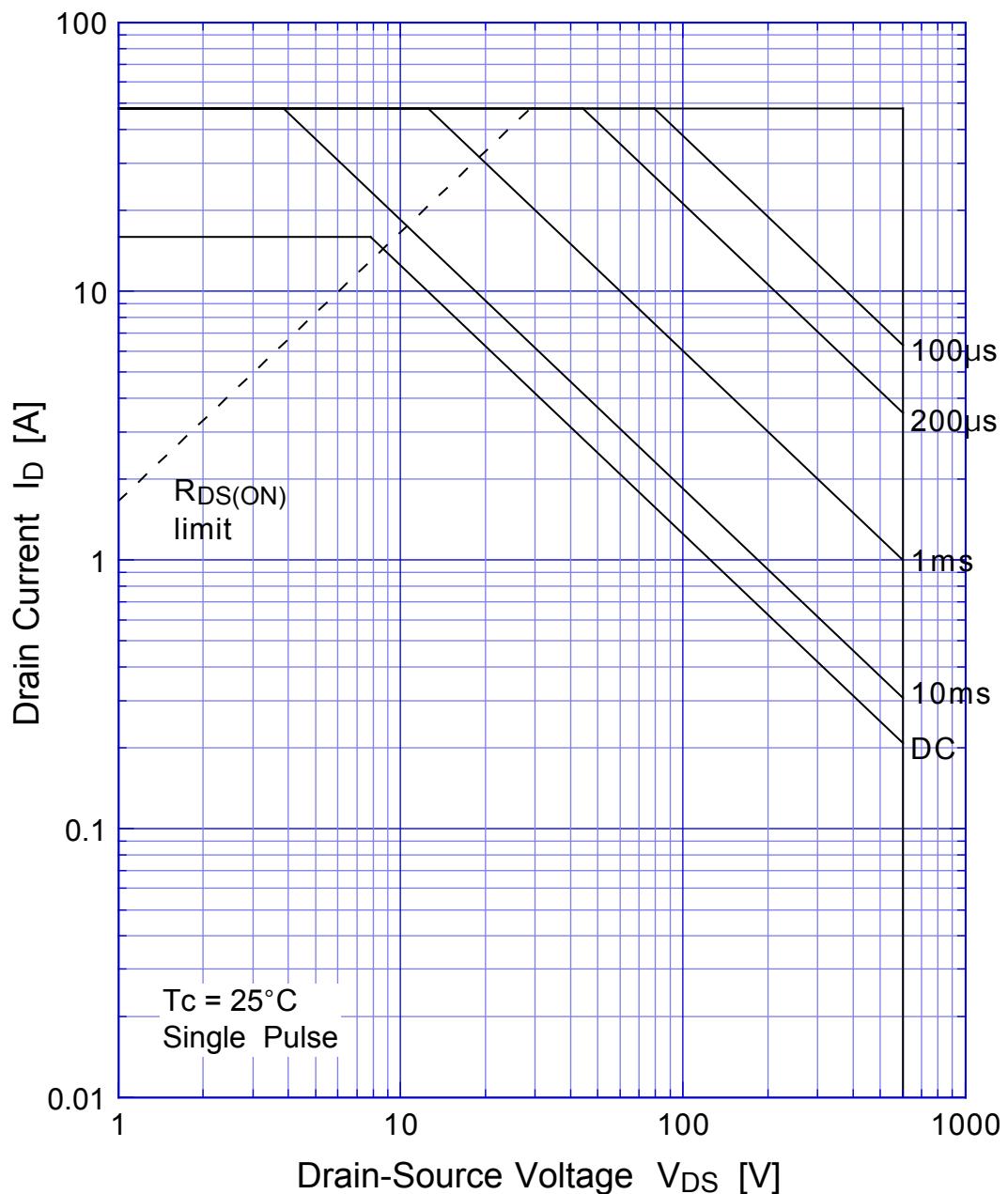
2SK3012 Static Drain-Source On-state Resistance



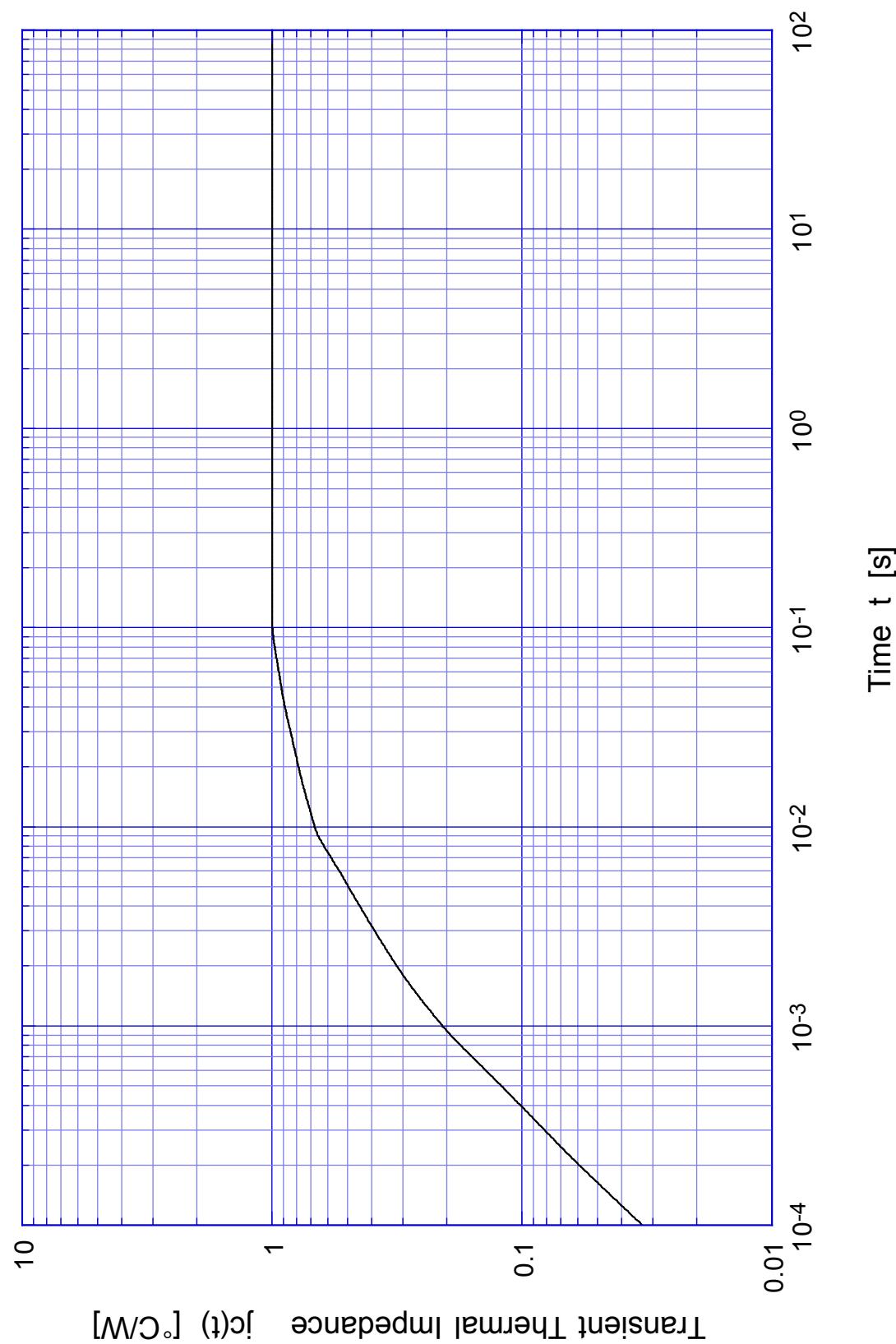
2SK3012 Gate Threshold Voltage



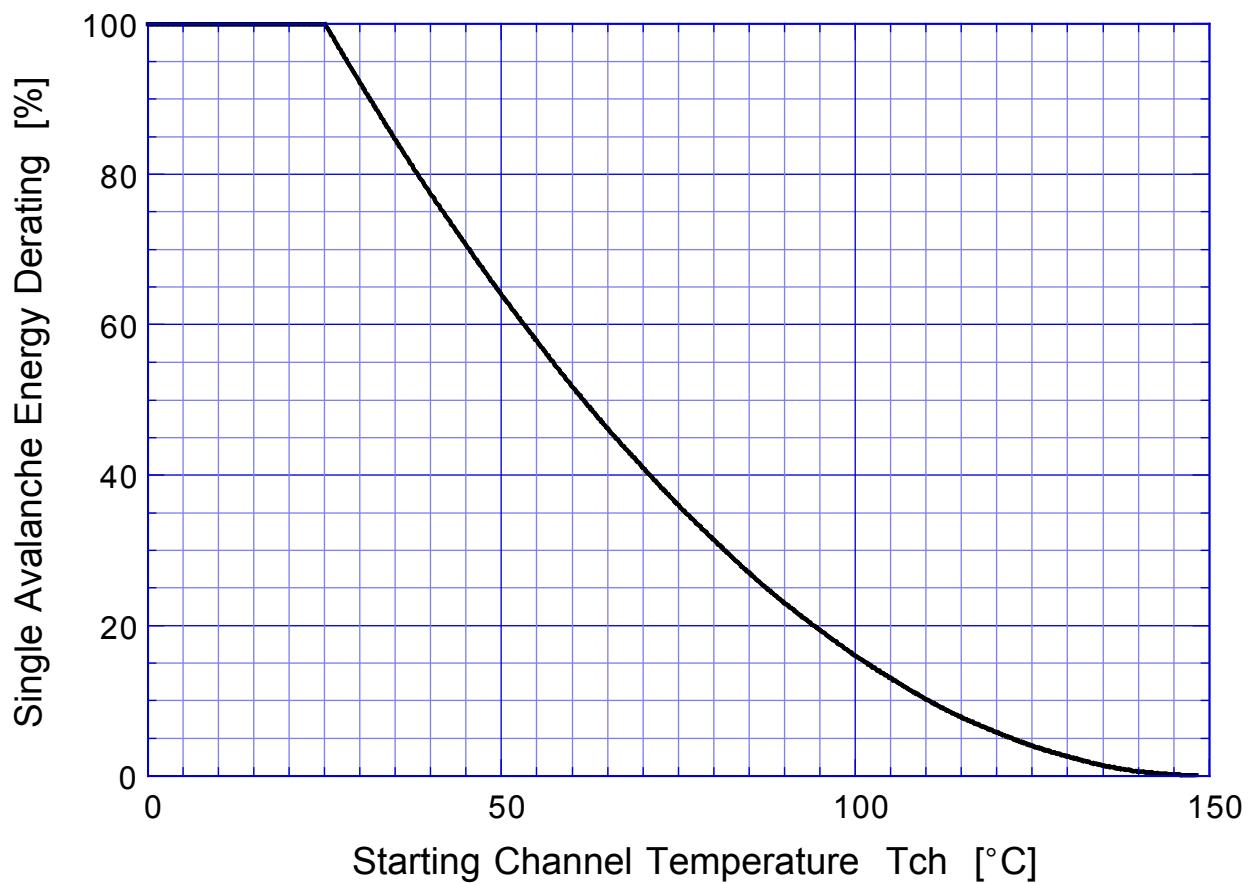
2SK3012 Safe Operating Area



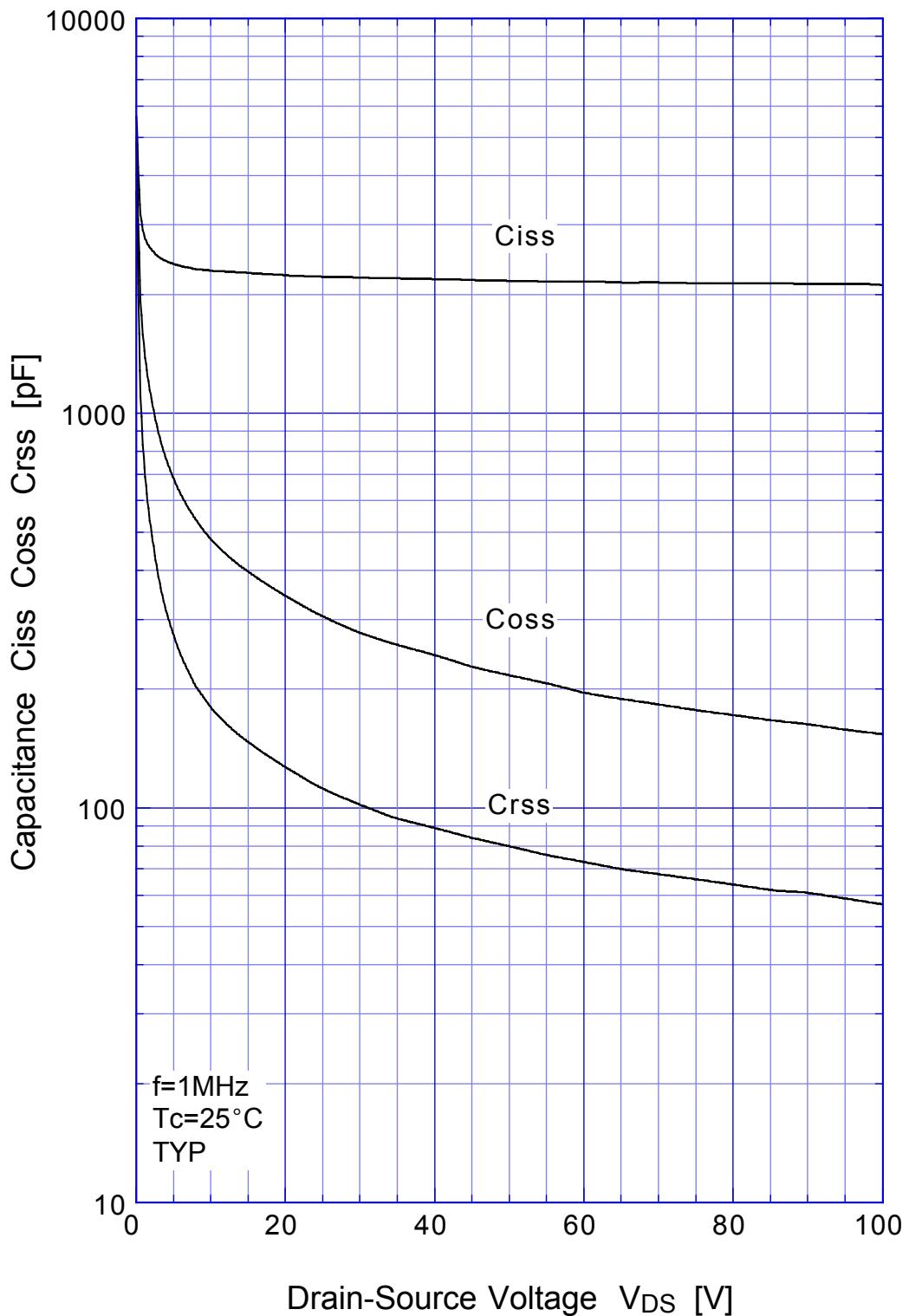
2SK3012 Transient Thermal Impedance



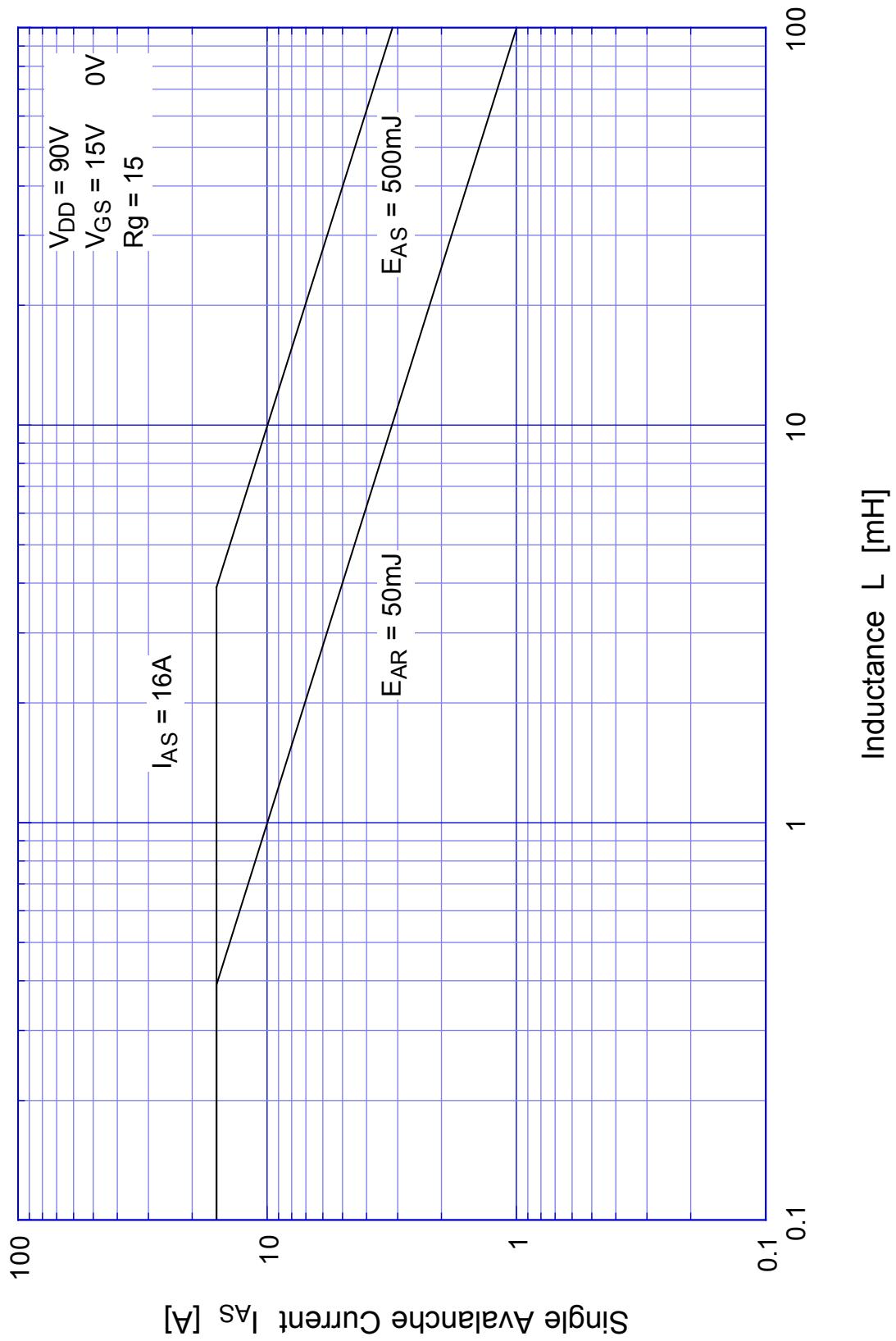
2SK3012 Single Avalanche Energy Derating



2SK3012 Capacitance

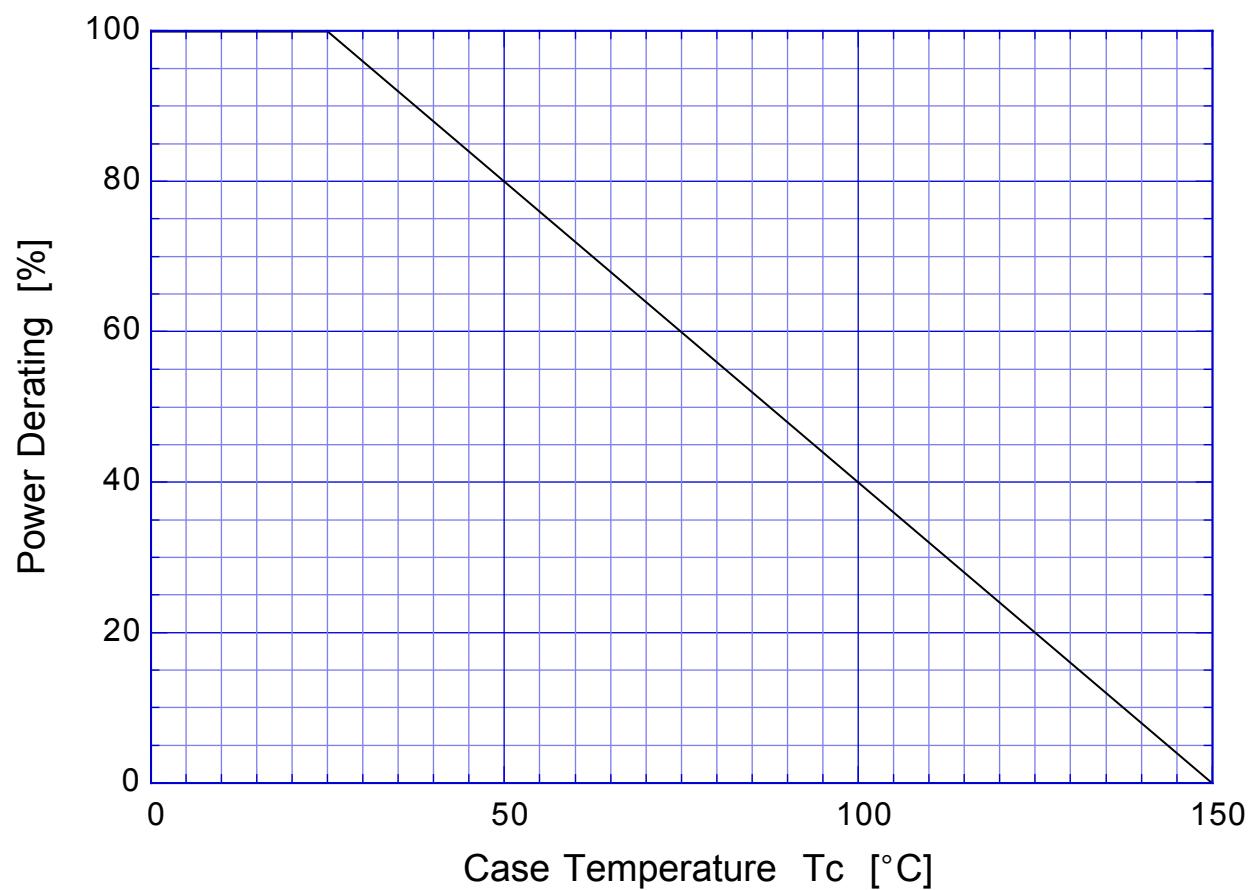


2SK3012 Single Avalanche Current - Inductive Load



2SK3012

Power Derating



2SK3012

Gate Charge Characteristics

